



OPTO-ELECTRONIC DEVICES DIVISION ELECTRONIC COMPONENTS GROUP SHARP CORPORATION

SPECIFICATION

(DEVICE SPECIFICATION FOR					
		OPIC LIGHT DETECTOR				
	MODEL No.	IS471FE				
	<u> </u>					

Specified for

Enclosed please find copies of the Specifications which consists of 12 pages including cover. After confirmation of the contents, please be sure to send back ______ copy of the Specifications with approving signature on each.

CUSTOMER'S APPROVAL

PRESENTED

DATE

ΒY

DATE

K.0 BY

H. Ogura, Department General Manager of Engineering Dept.,III Opto-Electronic Devices Div. ELECOM Group SHARP CORPORATION



Model No. : IS471FE

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2.	When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets, as well as the precautions mentioned below. Sharp assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets, and the precautions mentioned below.
	 (Precautions) (1) This product is designed for use in the following application areas ; (1) OA equipment · Audio visual equipment · Home appliances · Telecommunication equipment (Terminal) · Measuring equipment · Tooling machines · Computers (etc.) · 1// If the use of the product in the above application areas is for equipment listed in paragraphs (2) or (3), please be sure to observe the precautions given in those respective paragraphs.
	 (2) Appropriate measures, such as fail-safe design and redundant design considering the safety design of the overall system and equipment, should be taken to ensure reliability and safety when this product is used for equipment which demands high reliability and safety in function and precision, such as ; Transportation control and safety equipment (aircraft, train, automobile etc.) Traffic signals Gas leakage sensor breakers Rescue and security equipment
	 (3) Please do not use this product for equipment which require extremely high reliability and safety in function and precision, such as ; Space equipment • Telecommunication equipment (for trunk lines) • Nuclear power control equipment • Medical equipment
	(4) Please contact and consult with a Sharp sales representative if there are any questions regarding interpretation of the above three paragraphs.
3.	Please contact and consult with a Sharp sales representative for any questions about this product.

- Application This specification applies to the outline and characteristics of OPIC light detecting device; Model Na, ISAN JE 1. Application
- 2. Outline
- 3. Ratings and characteristics Refer to the attached sheet, page 4 to 7.
- 4. Reliability Refer to the attached sheet, page 8.
- 5. Outgoing inspection Refer to the attached sheet, page 9.
- 6. Supplement
 - (6-1) Equivalent circuit and Operating refer to the attached sheet, page 10.
 - (6-2) Packing refer to the attached sheet, page 11.
 - (6-3) This product is not designed against electromagnetic and ionized-particle irradiation.
 - (6-4) This product shall not contain the following materials. Also, the following materials shall not be used in the production process for this product. Materials for ODS : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methyl chloroform)
 - (6-5) This product and packaging material shall not contain lead material.
 - (6-6) Product mass (Piece): Approximately 0.18g
- 7. Notes
 - (7-1) By-pass capacitor

To avoid the malfunction by the power line noise, please place the capacitor above 0.33µF (f=1MHz) between Vcc-GND (1)-3terminals).

(7-2) Cleaning conditions :

Solvent temperature 45°C or less Immersion for 3 min or less Solvent cleaning :

The effect to device by ultrasonic cleaning differs by cleaning bath size, ultrasonic power Ultrasonic cleaning : output, cleaning time, PCB size or device mounting condition etc.

Please test it in actual using condition and confirm that doesn't occur any defect before starting

the ultrasonic cleaning.

The cleaning shall be carried out with solvent below.

Solvent : Ethyl alcohol, Methyl alcohol, Isopropyl alcohol

(7-3) Soldering

The lead pins should be soldered according to the absolute maximum ratings.

While or after soldering, the lead pins shall be free from external force.

This device shall not be soldered with preheat or reflow.

The terminal covering of this device consists of lead free solder.

In case of lead free soldering, please make sure that there is no problem in practical use since there is a possibility of boundary exfoliation (Lift-off phenomenon) between the solder and the land.



4/11 ED-05G041 IS471FE

3. Ratings and characteristics

3-1 Absolute maximum ratings

					Ta=25°C
	Par	ameter	· Symbol	Rating	Unit
Supply voltage			Vcc	-0.5~16	V
<u>*</u>	Output voltage		Vo	16	V
output	Output current		Io	50	mA
LED out	LED output Output voltage		V _{GL}	16	V
* ¹ Power dissipation			P	250	mW
Operating temperature Storage temperature		Topr	$-25 \sim +60$	<u>℃</u>	
		Tstg	$-40 \sim +100$	°C	
			Tsol	260	<u>°C</u>

*1. Power dissipation vs. ambient temperature is as per fig 5.

*2. Max 5sec at the position shown below.



Solderable

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Immersed to the bent angle

3-2 El	lectro-optical characteristics					· · · · · · · · · · · · · · · · · · ·	(V∞=5V, Ta=25°C)
	Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Conditions
;	Supply voltage	Vcc	4.5	-	16	V	
<u> </u>	Supply current	Icc	-	3.5	7.0	mA	Vo, GLo terminals are open.
	Low level output voltage	V _{OL}	-	0.15	0.35	V.	$I_{OL}=16mA$, $E_{VP}=500 lx$ $E_{VD}=0 lx$
Output	High level output voltage	V _{OH}	4.97	-	1	V	$E_{VP} = E_{VD} = 0 lx$ No.1
	Output short circuit current	I _{OS}	0.25	0.5	1.0	mA	$E_{VP} = E_{VD} = 0 lx \qquad \text{No.1}$
put	Low level output current	I _{GL}	40	55	70	mA	V _{GL} =1.2V
LED Output	* ¹ Pulse frequency	tp	70	130	220	μs	
	* ¹ Pulse width	tw	4.4	8	13.7	μs	
* ² " L→H " threshold radiation illuminance		E _{ePLH}	-	0.4	2.66	μ W/mm ²	$\begin{array}{llllllllllllllllllllllllllllllllllll$
* ² " H→L " threshold radiation illuminance		E _{ePHL}	-	0.7	2.8	µW/mm ²	$E_{eD}=0\mu W/mm^2 No.1,2$ LED($\lambda_{P}=940nm$)
Hysteresis		E _{PLH} /E _{PHL}	0.45	0.65	0.95	-	
se time	"H→L" propagation time	t _{PHL}	-	400	670		No.2
Response time	"L→H" propagation time	t _{PLH}		400	670	- μs	110,2
* ³ Permissible disturbance illuminance E		E _{VDX}	2000	7500	-	k	E _{ep} =7.5µW/mm ² , λ _p =940m

*1 The definition of Pulse frequency(tp) and Pulse width (tw) are shown in fig. 1.

The wave form of fig. 1 shows the output voltage wave of GLo terminal of the diagram of fig 2.



*2 "L \rightarrow H" ("H \rightarrow L") threshold radiation illuminance

- It shows E_{eP} when output changes to $L \rightarrow H (H \rightarrow L)$.
- *3 E_{VDX} : Limit of E_{VD} that this device works normally.

 E_{VP} shows the illuminance of signal light syncronized with the low level timing of GL_0 terminal output. E_{VD} shows the illuminance of direct current light. The light source is according to CIE standard. Measurement conditions



No.1 E_{eP}, E_{eD}

 E_{eP} shows the illuminance of signal light syncronized with the low level timing of GL_0 terminal output. E_{eD} shows the illuminance of direct current light. Fig 3 shows the details. The light source is LED ($\lambda_P = 940$ nm)



(Note) It shows the GLo terminal's waveform at fig 2 diagram.

No.2 Response time, Threshhold radiation illimance

Fig 4 shows the measuring circuit of response time, threshold radiation illuminance.





LED: peak emission wavelength $\lambda_p=940$ nm.



(Fig.6) Spectral sensitivity (TYP)







Confidence level : 90%

4. Reliability

The reliability of products shall satisfy items listed below.

		LTPD : 10 (or 20
Test Items	Test Conditions	Failure Judgement Criteria	Samples (n) Defective(C)
Temperature cycling	1 cycle $-40^{\circ}C \longleftrightarrow +100^{\circ}C$ (20min) (20min) 20 cycles test		n=22, C=0
High temp. and high humidity storage	+60°C,90%RH,1000h		n=22, C=0
High temp. storage	+100°C, 1000h	More than $U \times 1.2$ Less than $L \times 0.8$	n=22, C=0
Low temp. storage	-40°C, 1000h	n=22, C=0	
Operation test	V _{cc} =5V, Ta=25°C, 1000h		n=22, C=0
Mechanical shock	1000m/s ² , 6ms, Half sine wave 3 times/ $\pm X$, $\pm Y$, $\pm Z$ direction	U: Upper specification limit	
Variable frequency vibration	100 to 2000 to 100Hz/Sweep for approx. 4min 200m/s ² , 48min/X, Y, Z direction	L: Lower specification limit	n=11, C=0
Electrostatic withstand voltage	±200V, 200pF Once each terminal (V _{cc} ,GND reference)		n=11, C=0
Soldering heat	$260\pm5^{\circ}$, 5 ± 0.5 s Immersed to the bent angle	· · · · · · · · · · · · · · · · · · ·	n=11, C=0
Solderability	245±5℃, 5±1 s Immersed to the bent angle Flux:EC-19S (Tamura kaken corporation) No pretreatment	Solder shall adhere at less than 95% area of dipped portion.	n=11, C=0



Solderable

Immersed to the bent angle

5. Outgoing inspection

- (1) Inspection parameter
 - a. Electro-optical characteristics

Parameter		Symbol	MIN.	TYP.	MAX.	Unit	Conditions	
Supply voltage		Vcc	4.5	-	16	V		
	Supply current	Icc	1	3.5	7.0	mA	Vo, GL ₀ terminals are open	
	Low level output voltage	Vol	-	0.15	0.35	V	I_{OL} =16mA, E_{VD} =500 lx E_{VD} =0 lx	
Output	High level output voltage	V _{OH}	4.97		-	V	$E_{VP} = E_{VD} = 0 lx$ No.1	
	Output short circuit current	I _{OS}	0.25	0.5	1.0	mA	$E_{VP} = E_{VD} = 0 lx$ No.1	
Output	Low level output current	I _{GL}	40	55	70	mA	V _{GL} =1.2V	
	* ¹ Pulse frequency	t _P	70	130	220	μs		
LED	* ¹ Pulse width	tw	4.4	8	13.7	μs		
* ² " L→H " threshold radiation illuminance		E _{ePLH}	-	0.4	2.66	µW/mm²	$E_{eD}=0\mu W/mm^2$ No.1,2 LED($\lambda_P=940mm$)	
* ² " H→L " threshold radiation illuminance		E _{ePHL}		0.7	2.8	µW/mm ²	$E_{\text{eD}}=0\mu W/\text{mm}^2 \text{ No.1,2}$ $\text{LED}(\lambda_{\text{P}}=940\text{nm})$	
Hysteresis		E _{ePLH} /E _{ePHL}	0.45	0.65	0.95	-		
se time	"H→L" propagation time	t _{PHL}	-	400	670		No.2	
Response time	"L→H" propagation time	t _{PLH}	-	400	670	μs	110.2	
* ³ Permissible disturbance illuminance		E _{vDX}	2000	7500	-	lx	$E_{ep}=7.5 \mu W/mm^2$, $\lambda_{p}=940 nm$	

REFERENCE

b.Appearance

Defects	Judgement criteria
Cracks of product (resin area)	The cracks above 1mm size, and cracks over the lead frame are defects.

* The appearance should not affect the electrical, optical characteristics.

(2) Sampling method and inspection criteria

ISO 2859 one time sampling

Defects	Judgement criteria	AQL(%)
Major defects (Electro-optical characteristics defects, Assembly defects)	Normal inspection level Π	0.1
Minor defects (Appearance defects)	Normal inspection level II	0.25



6-1 Equivalent circuit and Operating

(6-1-1) Equivalent circuit



(6-1-2) Operating (True value)

Input	Output
Light ON	Low level
Light OFF	High level



- ② Inner packing material : Antistatic electricity bag (Polyethylene)
- (3) Quantity : 500pcs./bag

6-2-2 Outer packing



② Outer material : Packing case (Corrugated cardboard), Malt plane (Urethane), Cellophane tape

- ③ Quantity: 2000pcs./box
- ④ Indication : Model No., quantity and inspection date
- (5) Regular packaged mass : Approximately 430g